## 2025년 **2**월 **12**일(수)-**14**일(금) | 강원도 하이원리조트

### Future Normal in Semiconductor

2025-02-13(목), 09:00-10:45

좌장: 추후업데이트 예정

#### J. Nano-Science & Technology 분과

#### [TG1-J] 2D Materials & Devices

	Hypotaxy of Wafer-scale Single Crystal Transition Metal
초청 TG1-J-1 09:00-09:30	Dichalcogenides for Advanced Electronics
	Gwan-Hyoung Lee
	Department of Materials Science and Engineering, Seoul National University
TG1-J-2 09:30-09:45	Boltzmann Switching MoS <sub>2</sub> Metal-Semiconductor Field-Effect
	Transistors Enabled by Monolithic-Oxide-Gapped Metal Gates at the
	Schottky-Mott Limit
	Yeon Ho Kim <sup>1</sup> , Wei Jiang <sup>2</sup> , Tony Low <sup>2</sup> , Donghoon Moon <sup>3</sup> , Gwan-Hyoung Lee <sup>3</sup> , and Chul-Ho Lee <sup>3</sup>
	<sup>1</sup> Korea University, <sup>2</sup> University of Minnesota, <sup>3</sup> Seoul National University
	Direct Metallization on Cauterized Two-dimensional Semiconductors
	for Low-resistance p-type Contacts
	Woo-Ju Lee <sup>1,2</sup> , Kyu-myung Lee <sup>3</sup> , GunWoo Yoo <sup>1,2</sup> , TaeJoon Mo <sup>1,2</sup> , Yongsup Park <sup>3,4</sup>
TG1-J-3	and Cheool-Joo Kim <sup>1,2</sup>
09:45-10:00	<sup>1</sup> Center for Van der Waals Quantum Solids, Institute for Basic Science (IBS),
	<sup>2</sup> Department of Chemical Engineering, POSTECH, <sup>3</sup> Department of Physics and
	Institute of Basic Sciences, Kyung Hee University, <sup>4</sup> Department of Information
	Display, Kyung Hee Universi
	Semimetal Contact Engineering for Low-Noise, High-Performance
	WSe <sub>2</sub> -Based Phototransistors
	Sunggyu Ryoo <sup>1</sup> , Jinwoo Sim <sup>1</sup> , Jaeyong Woo <sup>1</sup> , Jaehyoung Park <sup>1</sup> , Yeeun Kim <sup>1</sup> ,
TG1-J-4	Youngmin Song <sup>1</sup> , Heebeom Ahn <sup>2</sup> , Kyungjune Cho <sup>3</sup> , and Takhee Lee <sup>1</sup>
10:00-10:15	<sup>1</sup> Department of Physics and Astronomy, Seoul National University, <sup>2</sup> Department of
	Materials Science and Engineering, Seoul National University, <sup>3</sup> Convergence
	Research Center for Solutions to Electromagnetic Interference in Future-Mobility,
	KIST
TG1-J-5	   양극성 이황화 몰리브덴 기반 자가구동 광검출기
	송준기 <sup>1</sup> , 황재하 <sup>1</sup> , 이수연 <sup>1</sup> , 장한별 <sup>2</sup> , 이가영 <sup>1</sup>
10:15-10:30	8년기, 8세이, 이루면, 8년일, 이기8   <sup>1</sup> 한국과학기술원, <sup>2</sup> 광주과학기술원

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TG1-J-6 10:30-10:45	Unique Electrical Properties of Junctionless Electric-Double-Layer
	MoS <sub>2</sub> Transistor with Electrostatically Highly Doped Channel
	Dae Young Jeon <sup>1</sup> , Jimin Park <sup>2</sup> , So Jeong Park <sup>3</sup> , and Gyu Tae Kim <sup>4</sup>
	<sup>1</sup> Gyeongsang National University, <sup>2</sup> KIST Jeonbuk, <sup>3</sup> Korean Intellectual Property
	Office, <sup>4</sup> Korea University